

69
Gould


wherein said at least ~~one~~ thin film transistor and said at least another one thin film transistor are formed from a common semiconductor film formed over said insulating substrate.

REMARKS

This amendment is submitted to supplement applicant's response of November 12, 1995. Specifically, this supplemental amendment merely amends claim 1 at line 13, changing "driving means" to "driving circuit" and claim 13 at line 9, changing "control means" to "control circuit." Accordingly, it is believed that the present application is now in condition for allowance and favorable consideration is requested in view of the above amendments.

If the Examiner has any questions concerning this application or believes that any further discussions would expedite the prosecution thereof, it is requested that the undersigned be contacted.

Respectfully submitted,


Eric J. Robinson
Reg. No. 38,285

Sixbey, Friedman, Leedom & Ferguson, P.C.
2010 Corporate Ridge, Suite 600
McLean, Virginia 22102
(703) 790-9110